

## Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- Green Device Available

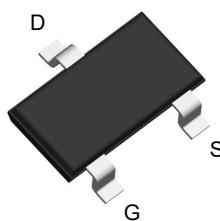
## Product Summary



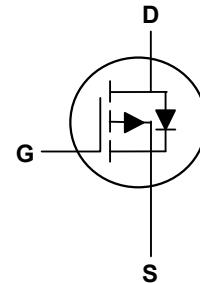
$V_{DS}$	-20	V
$I_D$	-4.5	A
$R_{DS(ON)}$ (at $V_{GS}=-4.5V$ )	40	mΩ
$R_{DS(ON)}$ (at $V_{GS}=-2.5V$ )	50	mΩ

## Applications

- High Frequency Point-of-Load,Synchronous Buck Converter
- Networking DC-DC Power System
- Load Switch



SOT23 Top View



## Absolute Maximum Ratings( $T_A=25^\circ C$ , unless otherwise noted)

Parameter	Symbol	Rating	Units
Drain-Source Voltage	$V_{DS}$	-20	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	V
Continuous Drain Current	$I_D$	-4.5	A
Pulsed Drain Current <sup>2</sup>	$I_{DM}$	-20	A
Total Power Dissipation	$P_D$	1.7	W
Storage Temperature Range	$T_{STG}$	-55 to 150	°C
Operating Junction Temperature Range	$T_J$	-55 to 150	°C

## Thermal Characteristics

Parameter	Symbol	Typ	Max	Unit
Thermal Resistance Junction-Ambient <sup>1</sup>	$R_{\theta JA}$	---	73.5	°C/W

**Electrical Characteristics ( $T_J=25^\circ\text{C}$ , unless otherwise noted)**

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}}=0\text{V}$ , $I_D=-250\mu\text{A}$	-20	---	---	V
Static Drain-Source On-Resistance	$R_{\text{DS(ON)}}$	$V_{\text{GS}}=-4.5\text{V}$ , $I_D=-4\text{A}$	---	31	40	$\text{m}\Omega$
		$V_{\text{GS}}=-2.5\text{V}$ , $I_D=-2\text{A}$	---	37	50	$\text{m}\Omega$
		$V_{\text{GS}}=-1.8\text{V}$ , $I_D=-1\text{A}$	---	47	70	$\text{m}\Omega$
		$V_{\text{GS}}=V_{\text{DS}}$ , $I_D = -250\mu\text{A}$	-0.45	-0.7	-1	V
Gate Threshold Voltage	$V_{\text{GS(th)}}$	$V_{\text{GS}}=V_{\text{DS}}$ , $I_D = -250\mu\text{A}$	-0.45	-0.7	-1	V
Drain-Source Leakage Current	$I_{\text{DSS}}$	$V_{\text{DS}}=-20\text{V}$ , $V_{\text{GS}}=0\text{V}$ , $T_J=25^\circ\text{C}$	---	---	-1	$\mu\text{A}$
Gate-Source Leakage Current	$I_{\text{GSS}}$	$V_{\text{GS}}=\pm 12\text{V}$ , $V_{\text{DS}}=0\text{V}$	---	---	$\pm 100$	nA
Forward Transconductance	$g_{\text{fs}}$	$V_{\text{DS}}=-5\text{V}$ , $I_D=-4.1\text{A}$	---	13	---	S
Total Gate Charge	$Q_g$	$V_{\text{DS}}=-10\text{V}$ , $V_{\text{GS}}=-4.5\text{V}$ , $I_D=-4\text{A}$	---	14.5	---	nC
Gate-Source Charge	$Q_{\text{gs}}$		---	2.2	---	
Gate-Drain Charge	$Q_{\text{gd}}$		---	2.5	---	
Turn-On Delay Time	$T_{\text{d(on)}}$	$V_{\text{DD}}=-10\text{V}$ , $R_L=2.2\Omega$ , $V_{\text{GS}}=-4.5\text{V}$ , $R_G=1\Omega$ , $I_D=-3.2\text{A}$	---	23	---	ns
Rise Time	$T_r$		---	25	---	
Turn-Off Delay Time	$T_{\text{d(off)}}$		---	55	---	
Fall Time	$T_f$		---	13	---	
Input Capacitance	$C_{\text{iss}}$	$V_{\text{DS}}=-15\text{V}$ , $V_{\text{GS}}=0\text{V}$ , $f=1\text{MHz}$	---	1159	---	pF
Output Capacitance	$C_{\text{oss}}$		---	133	---	
Reverse Transfer Capacitance	$C_{\text{rss}}$		---	118	---	

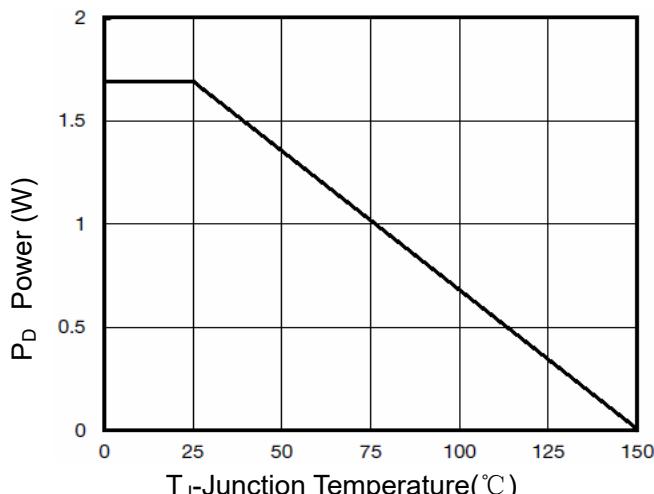
**Drain-Source Diode Characteristics**

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Continuous Source Current <sup>2</sup>	$I_s$		---	---	-5.3	A
Diode Forward Voltage <sup>1</sup>	$V_{\text{SD}}$	$V_{\text{GS}}=0\text{V}$ , $I_s=-5.3\text{A}$ , $T_J=25^\circ\text{C}$	---	---	-1.2	V

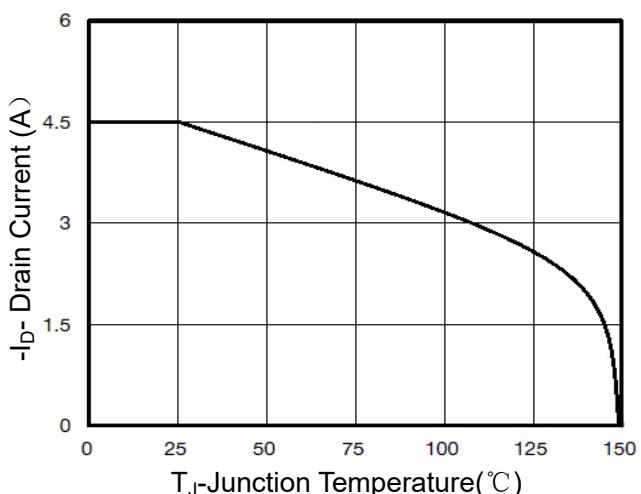
**Note:**

- 1.The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper.
- 2.The data tested by pulsed , pulse width  $\leq 300\text{us}$  , duty cycle  $\leq 2\%$

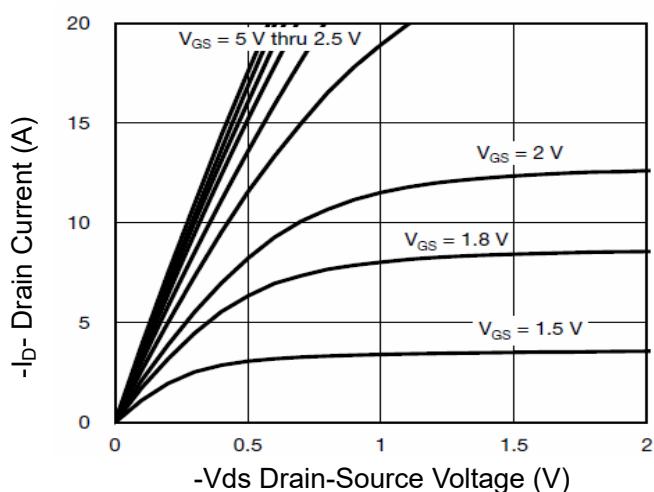
## Typical Characteristics



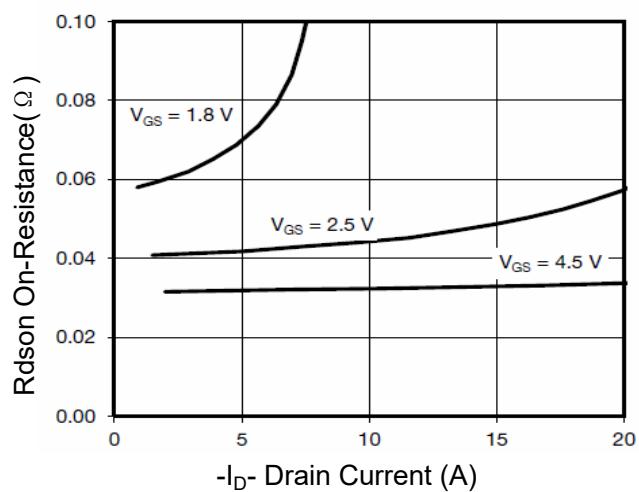
**Figure 1 Power Dissipation**



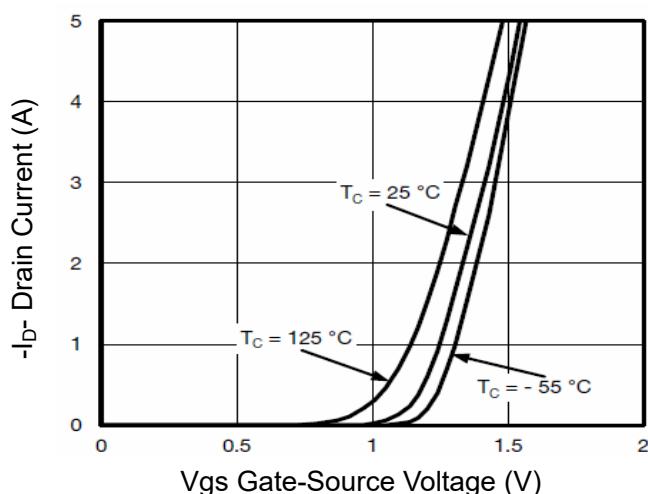
**Figure 2 Drain Current**



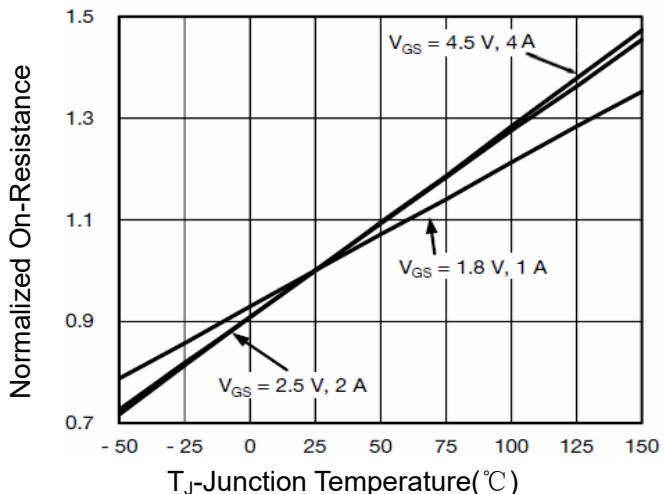
**Figure 3 Output Characteristics**



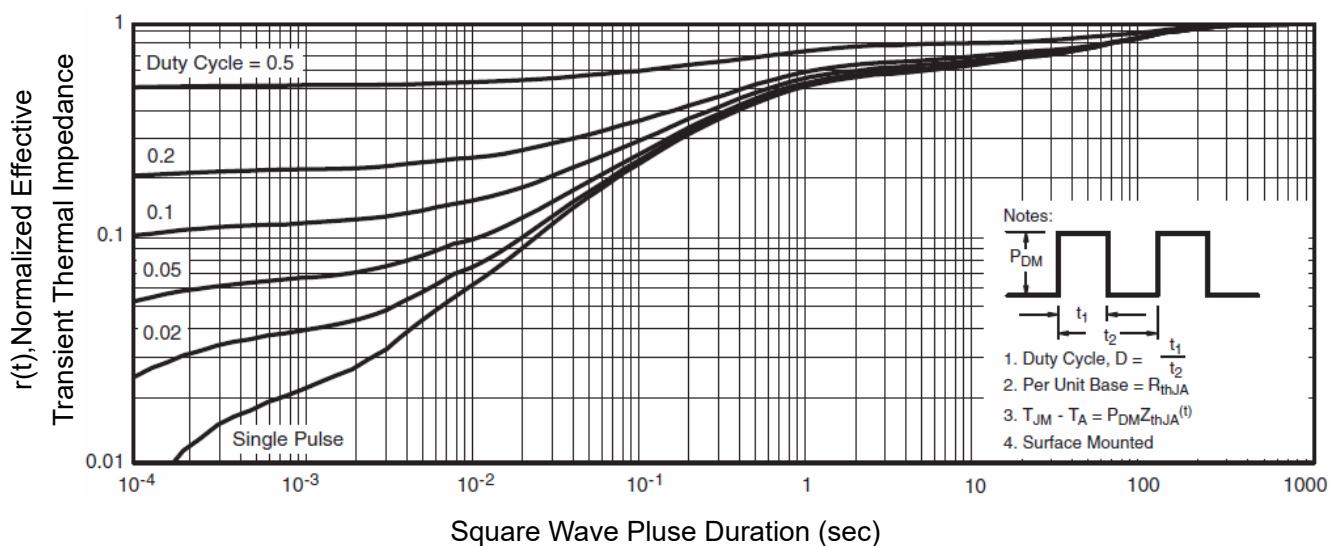
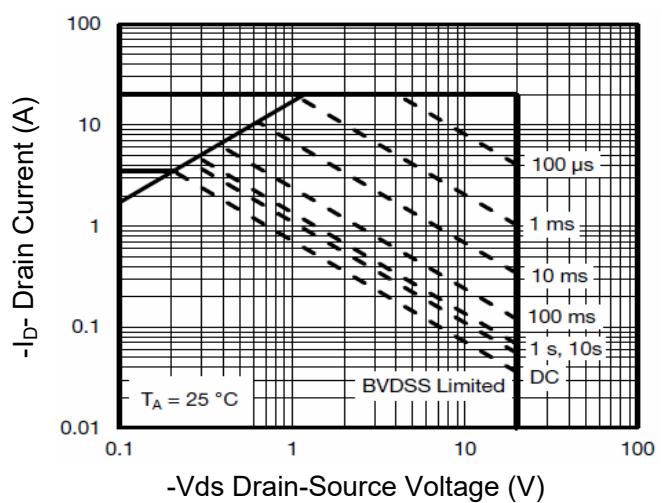
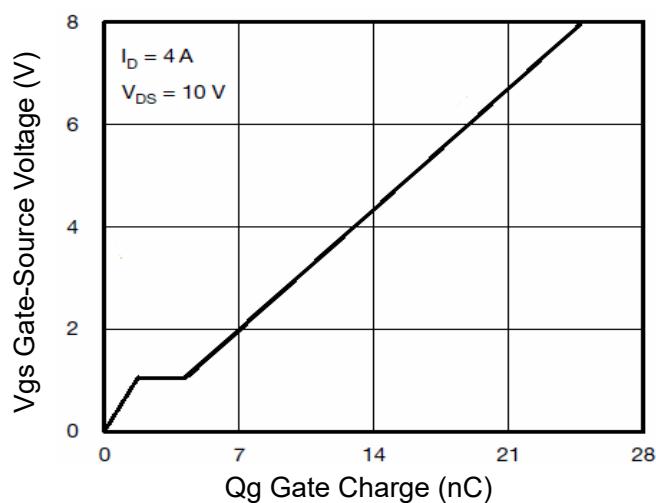
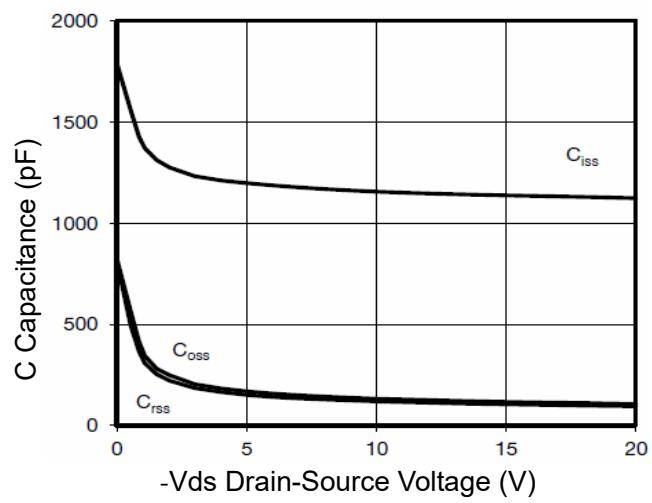
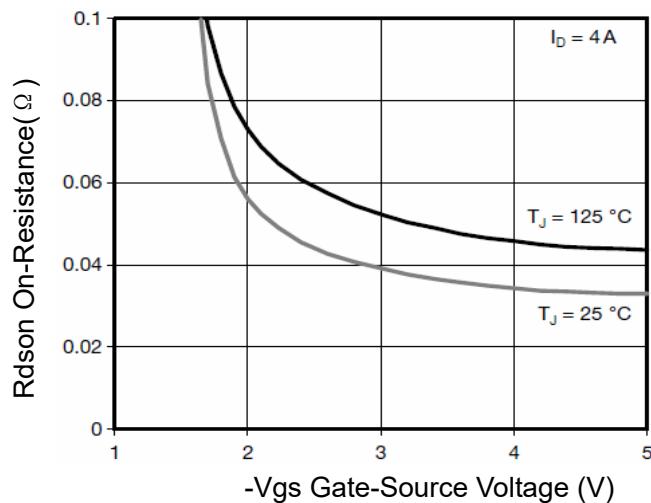
**Figure 4 Drain-Source On-Resistance**



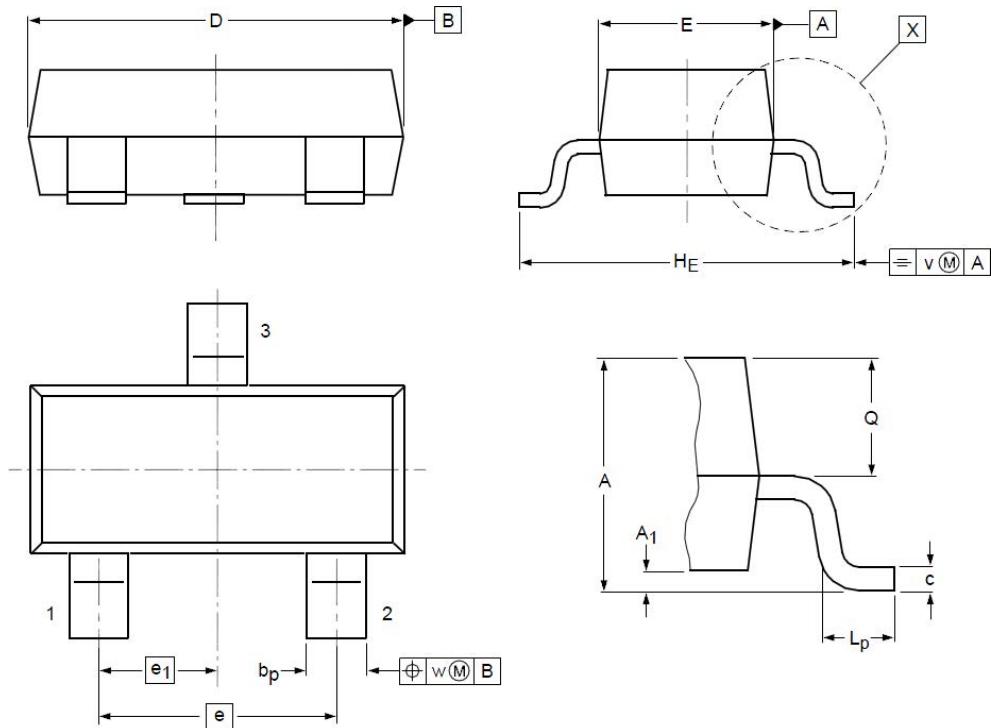
**Figure 5 Transfer Characteristics**



**Figure 6 Drain-Source On-Resistance**



### SOT23 Package Outline Dimensions



<b>Symbol</b>	<b>Dimensions (unit:mm)</b>			<b>Symbol</b>	<b>Dimensions (unit:mm)</b>		
	<b>Min</b>	<b>Typ</b>	<b>Max</b>		<b>Min</b>	<b>Typ</b>	<b>Max</b>
<b>A</b>	0.90	1.05	1.20	<b>e<sub>1</sub></b>	--	0.95	--
<b>A<sub>1</sub></b>	0.01	0.05	0.10	<b>H<sub>E</sub></b>	2.10	2.40	2.50
<b>b<sub>p</sub></b>	0.38	0.42	0.48	<b>L<sub>P</sub></b>	0.40	0.50	0.60
<b>c</b>	0.09	0.13	0.15	<b>Q</b>	0.45	0.49	0.55
<b>D</b>	2.80	2.92	3.00	<b>V</b>	--	0.20	--
<b>E</b>	1.20	1.33	1.40	<b>W</b>	--	0.10	--
<b>e</b>	--	1.90	--				